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A. Patent Application No.(s)	B. Patent No.(s)
7,241,699	Pub 5th 2012
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Invention Title:	Silicon Carbide Bipolar Junction Transistor Fabrication Processes
Inventor(s):	John Torvik Ivan Perez Bart J. Van Zeghbroeck
Patent or Application Serial No,:	7,241,699
entitled	Wide Bandgap Semiconductor Device Construction
U.S. Filing/Issue Date:	07/10/2007
Grant/Contract Identification Number(s):	N00014-99-C-0332

Foreign Applications filed/intended ln (countries):

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